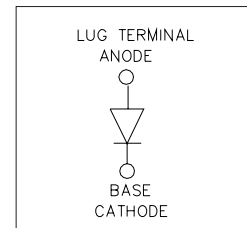


International
IOR Rectifier

121NQ045PbF

SCHOTTKY RECTIFIER

120Amp



Major Ratings and Characteristics

Characteristics	Values	Units
$I_{F(AV)}$ Rectangular waveform	120	A
V_{RRM}	45	V
I_{FSM} @ $t_p = 5 \mu s$ sine	16000	A
V_F @120Apk, $T_J = 125^\circ C$	0.6	V
T_J range	-55 to 175	$^\circ C$

Description/ Features

The 121NQ.. high current Schottky rectifier module series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to $150^\circ C$ junction temperature. Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, free-wheeling diodes, welding, and reverse battery protection.

- $175^\circ C$ T_J operation
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Lead-Free

Case Styles



HALF-PAK (D-67)

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Voltage Ratings

Part number	121NQ045PbF
V_R Max. DC Reverse Voltage (V)	45
V_{RWM} Max. Working Peak Reverse Voltage (V)	

Absolute Maximum Ratings

Parameters	121NQ	Units	Conditions		
$I_{F(AV)}$ Max.AverageForwardCurrent * See Fig. 5	120	A	50% duty cycle @ $T_C = 137^{\circ}\text{C}$, rectangular wave form		
I_{FSM} Max. Peak One Cycle Non-Repetitive Surge Current * See Fig. 7	16000	A	5 μs Sine or 3 μs Rect. pulse	Following any rated load condition and with rated V_{RRM} applied	
	2000		10ms Sine or 6ms Rect. pulse		
E_{AS} Non-Repetitive Avalanche Energy	81	mJ	$T_J = 25^{\circ}\text{C}$, $I_{AS} = 13$ Amps, $L = 1$ mH		
I_{AR} Repetitive Avalanche Current	13	A	Current decaying linearly to zero in 1 μsec Frequency limited by T_J max. $V_A = 1.5 \times V_R$ typical		

Electrical Specifications

Parameters		121NQ	Units	Conditions	
V _{FM}	Max. Forward Voltage Drop * See Fig. 1 (1)	0.65	V	@ 120A	T _J = 25 °C
		0.82	V	@ 240A	
		0.6	V	@ 120A	T _J = 125 °C
		0.76	V	@ 240A	
I _{RM}	Max. Reverse Leakage Current * See Fig. 2	10	mA	T _J = 25 °C	V _R = rated V _R
		90	mA	T _J = 125 °C	
C _T	Max. Junction Capacitance	5200	pF	V _R = 5V _{DC} (test signal range 100Khz to 1Mhz) 25°C	
L _S	Typical Series Inductance	7.0	nH	From top of terminal hole to mounting plane	
dv/dt	Max. Voltage Rate of Change (Rated V _R)	10000	V/ μs		

(1) Pulse Width = 500 μs

Thermal-Mechanical Specifications

Parameters			121NQ	Units	Conditions
T _J	Max. Junction Temperature Range		-55 to 175	°C	
T _{stg}	Max. Storage Temperature Range		-55 to 175	°C	
R _{thJC}	Max. Thermal Resistance Junction to Case		0.38	°C/W	DC operation * See Fig. 4
R _{thCS}	Typical Thermal Resistance, Case to Heatsink		0.05	°C/W	Mounting surface, smooth and greased
wt	Approximate Weight		30 (1.06)	g (oz.)	
T	Mounting Torque	Min.	3 (26.5)	Nm (lbf-in)	Non-lubricated threads
		Max.	4 (35.4)		
	Terminal Torque	Min.	3.4 (30)		
		Max.	5 (44.2)		
Case Style			HALF PAK Module		

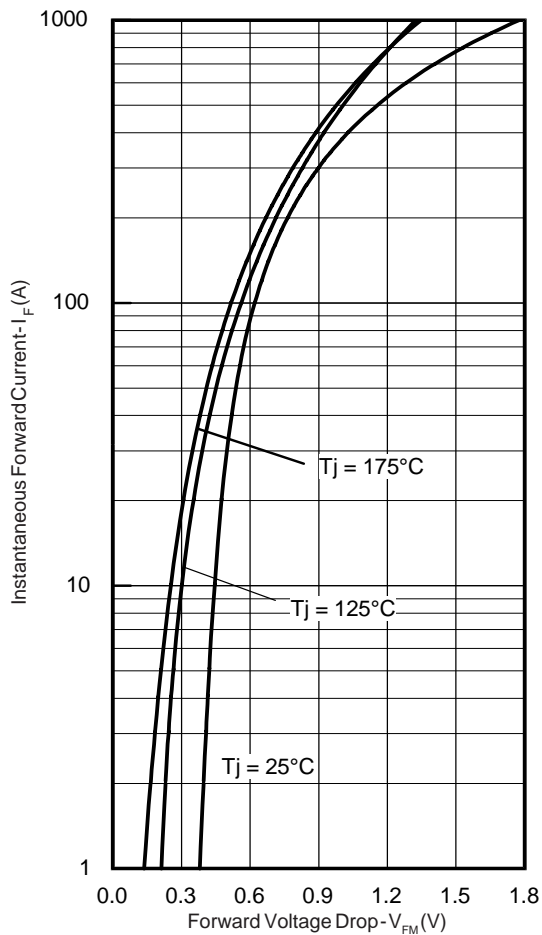


Fig. 1 - Max. Forward Voltage Drop Characteristics

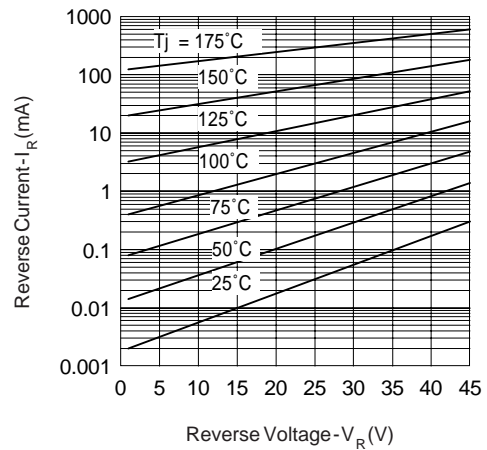


Fig. 2 - Typical Values Of Reverse Current Vs. Reverse Voltage

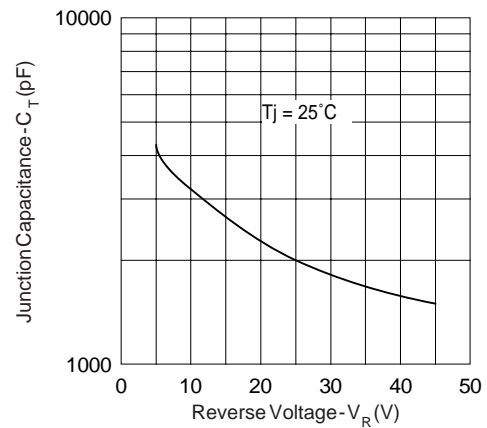


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

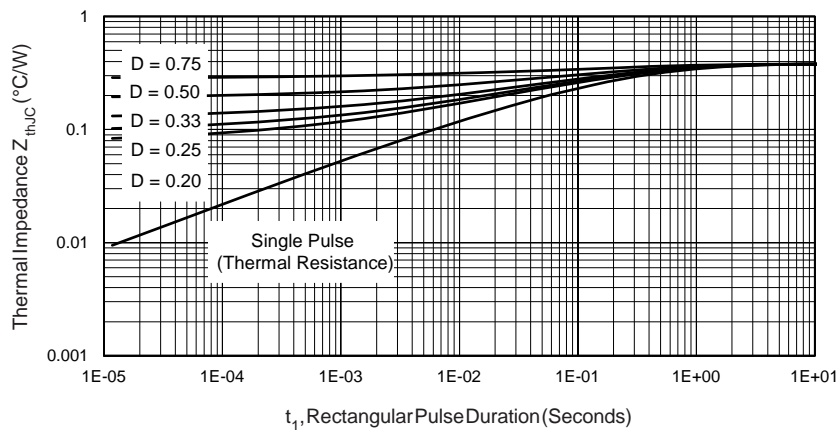


Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics

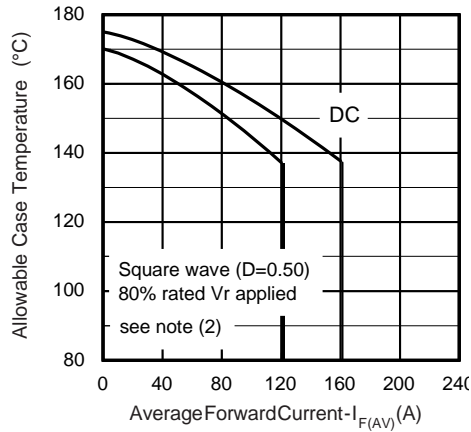


Fig. 5 - Max. Allowable Case Temperature Vs. Average Forward Current

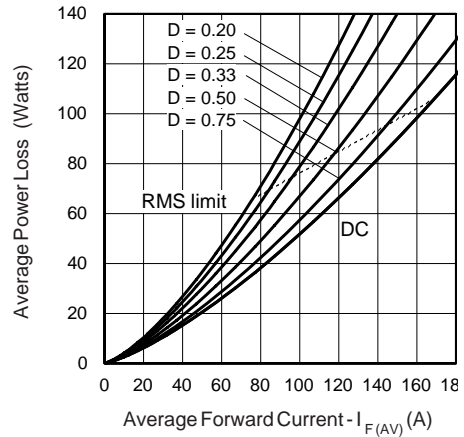


Fig. 6 - Forward Power Loss Characteristics

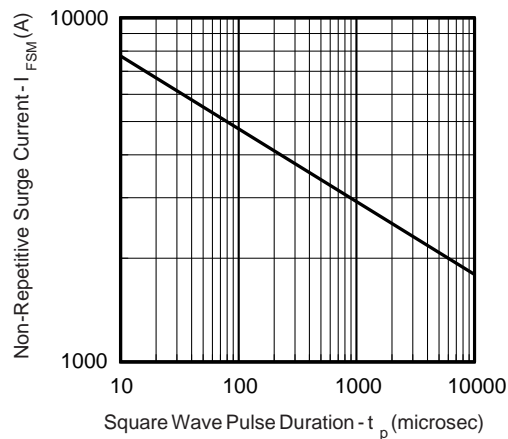


Fig. 7 - Max. Non-Repetitive Surge Current

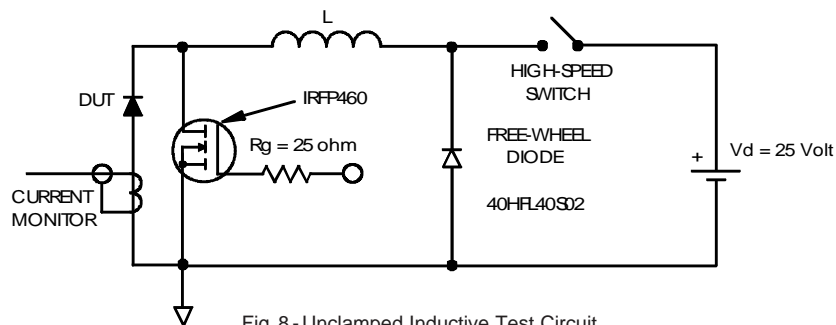


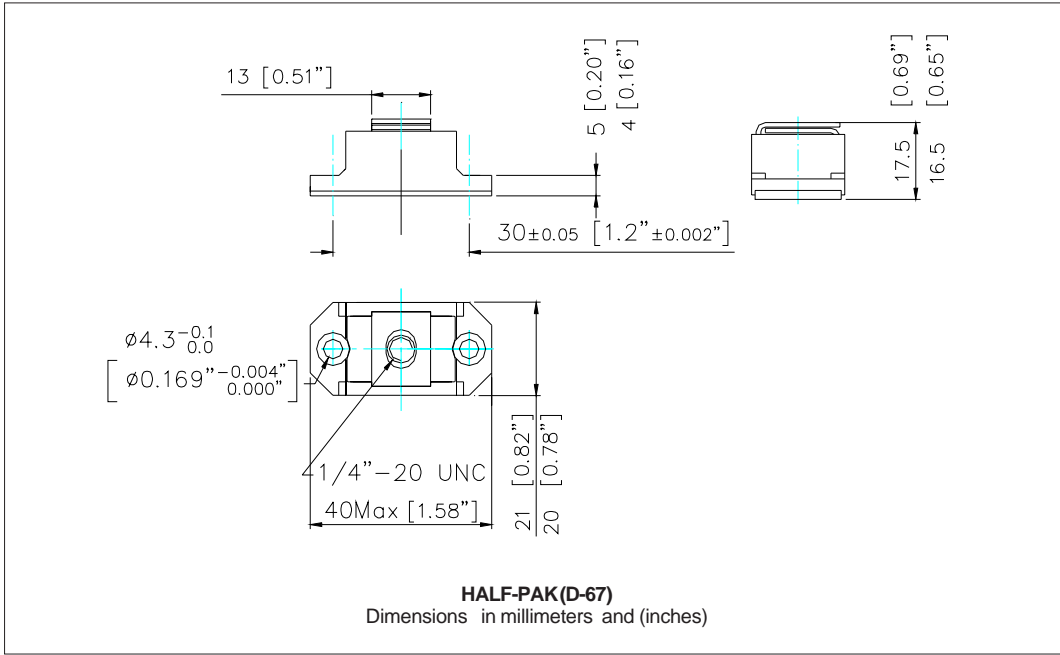
Fig. 8 - Unclamped Inductive Test Circuit

(2) Formula used: $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$;

P_d = Forward Power Loss = $I_{F(AV)} \times V_{FM} @ (I_{F(AV)}/D)$ (see Fig. 6);

$P_{d_{REV}}$ = Inverse Power Loss = $V_{R1} \times I_R (1 - D)$; $I_R @ V_{R1}$ = rated V_R

Outline Table



Ordering Information Table

Device Code					
12	1	N	Q	045	PbF
1	2	3	4	5	6
1	-	Average Current Rating (x 10)			
2	-	Product Silicon Identification			
3	-	N = NOt Isolated			
4	-	Q = Schottky Rectifier Diode			
5	-	Voltage Rating (045 = 45V)			
6	-	Lead-Free			

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Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level and Lead-Free.
Qualification Standards can be found on IR's Web site.

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IR WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245, USA Tel: (310) 252-7105
TAC Fax: (310) 252-7309
11/06



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